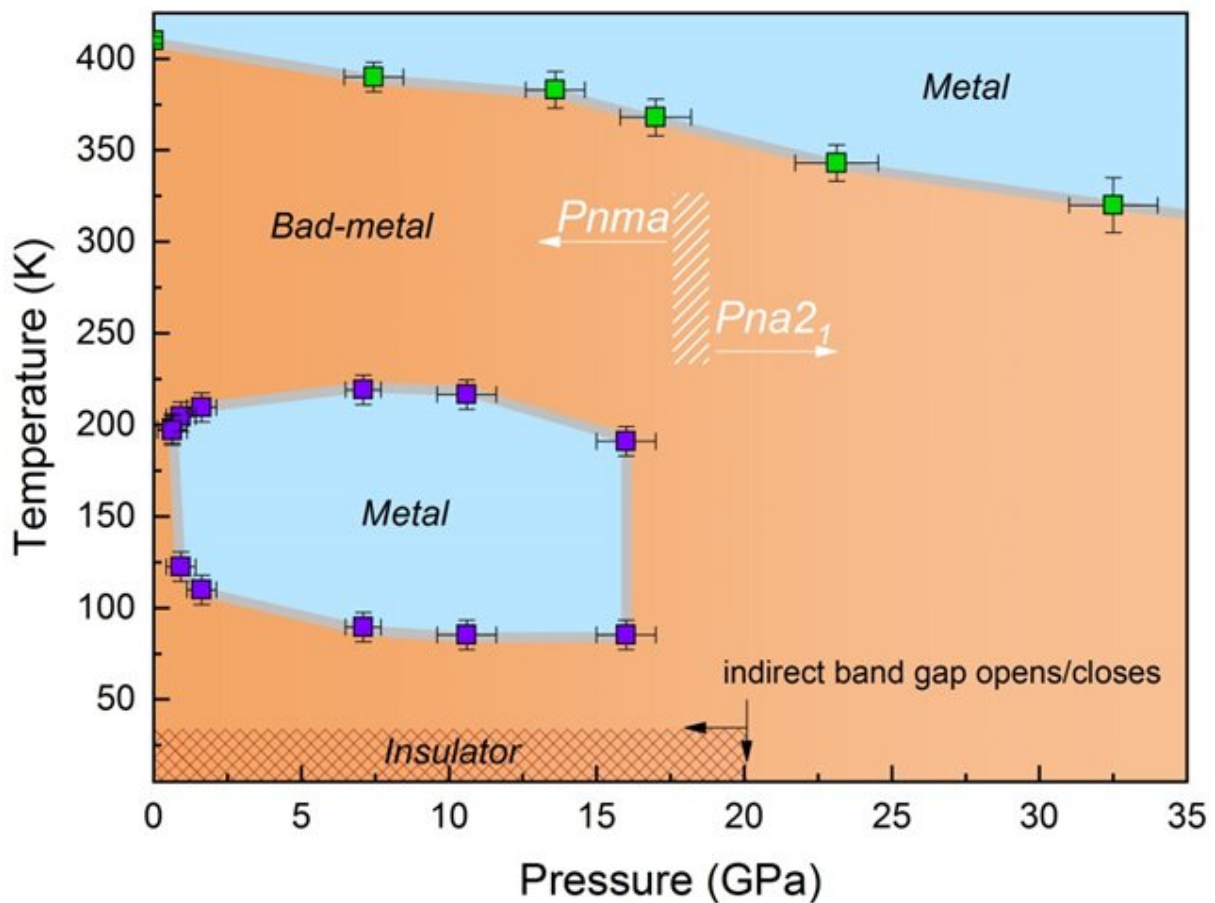


Aberrant electronic and structural alterations in pressure-tuned perovskite

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Electronic and structural phase diagram of NaOsO₃. Credit: Raimundas Sereika

The perovskite NaOsO₃ has a complicated but interesting temperature-

dependent metal-insulator transition (MIT). A team led by Drs. Raimundas Sereika and Yang Ding from the Center for High Pressure Science and Technology Advanced Research (HPSTAR) showed that the insulating ground state in NaOsO_3 can be preserved up to at least 35 GPa with a sluggish MIT reduction from 410 K to a near room temperature and possible transformation to a polar phase. The work has been published in *npj Quantum Materials*.

NaOsO_3 perovskite undergoes a metal-insulator transition concomitant with the onset of an antiferromagnetic long-range ordering at a Neel temperature of about 410 K, which is accompanied by a magnetic ordering without any lattice distortion.

The team carried out a combined experimental and computational study to understand the effect of external [pressure](#) on perovskite NaOsO_3 . They found hidden hysteretic resistance properties with a transient metallic state near 200 K. Also three electronic character anomalies (at 1.7, 9.0, and 25.5 GPa), and a structural transition to the singular polar phase (at ~ 18 GPa) were discovered.

In terms of the MIT, the pressure-dependent electrical transport measurements indicate that the metallic state extends to the [lower temperatures](#) very slowly. The TMIT scales almost linearly upon pressure. At around 32 GPa, the MIT becomes much broader, but can still be identified. Importantly, up to this pressure, NaOsO_3 preserves the insulating ground state.

In addition, the warming and cooling curves slightly deviate, forming a narrow thermal hysteresis loop below MIT. The hysteresis is progressively attenuated upon pressure but eventually disappears at about 18 GPa. "The observed hysteresis raises a question if MIT is really the second-order type that was initially assigned," Sereika said.

Further, when the pressure is increased, the Raman results show that NaOsO_3 experiences a structural change. The Raman spectra in particular demonstrate the enhancement of the number of phonons and the pressure-induced-splitting of phonon mode above 18 GPa.

"Our pressure-dependent Raman measurements support the fact that the crystal symmetry does not change up to 16 GPa at room temperature and indicates that further pressure increase causes structural transformation to a different symmetry," Ding explained.

"At about 26 GPa, the continuous large-scale reduction in intensity is observed as the pressure increases. Finally, the Raman modes almost vanish at 35 GPa, indicating that sample is approaching a metallic state, that is the MIT," Ding added.

By combining theoretical modeling and [experimental data](#) all observed phenomena were explained in detail. A rich electronic and structural phase diagram of NaOsO_3 shows the different types of transitions occurring in the system when pressure and temperature are applied: insulator-to-bad metal, bad-metal-to-metal, the anomalous metal island in the bad-metal region, and the subtle non-polar to polar structural transition.

At low temperature the system remains insulating up to a certain critical pressure (~20 GPa in DFT) and then transforms into a bad metal due to the closing of the indirect gap. In this pressure range the valence and conduction bands are still separated by a direct gap. This gap closes at very large pressure, indicating that the evolution of the electronic properties upon pressure share similarities with the [temperature](#)-induced band gap closing process.

"The magnetically itinerant Lifshitz-type mechanism with spin-orbit and spin-phonon interactions is responsible for these pressure-induced

changes," Ding said. "Our findings provide another new playground for the emergence of new states in 5-D materials by using high-pressure methods."

More information: Raimundas Sereika et al, Aberrant electronic and structural alterations in pressure tuned perovskite NaOsO₃, *npj Quantum Materials* (2020). [DOI: 10.1038/s41535-020-00269-3](https://doi.org/10.1038/s41535-020-00269-3)

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